

# MMBT4126LT1G

## General Purpose Transistor

### PNP Silicon

#### Features

- Moisture Sensitivity Level: 1
- ESD Rating: – Human Body Model: > 4000 V  
– Machine Model: > 400 V
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS

| Rating                       | Symbol    | Value | Unit |
|------------------------------|-----------|-------|------|
| Collector–Emitter Voltage    | $V_{CEO}$ | –25   | Vdc  |
| Collector–Base Voltage       | $V_{CBO}$ | –25   | Vdc  |
| Emitter–Base Voltage         | $V_{EBO}$ | –4    | Vdc  |
| Collector Current–Continuous | $I_C$     | –200  | mAdc |

#### THERMAL CHARACTERISTICS

| Characteristic  | Symbol          | Max         | Unit                       |
|---|-----------------|-------------|----------------------------|
| Total Device Dissipation FR–5 Board<br>(Note 1) @ $T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$         | $P_D$           | 225<br>1.8  | mW<br>mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction–to–Ambient<br>(Note 1)   | $R_{\theta JA}$ | 556         | $^\circ\text{C}/\text{W}$  |
| Total Device Dissipation Alumina<br>Substrate, (Note 2) @ $T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | $P_D$           | 300<br>2.4  | mW<br>mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction–to–Ambient<br>(Note 2)   | $R_{\theta JA}$ | 417         | $^\circ\text{C}/\text{W}$  |
| Junction and Storage Temperature Range  | $T_J, T_{stg}$  | –55 to +150 | $^\circ\text{C}$           |

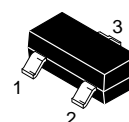
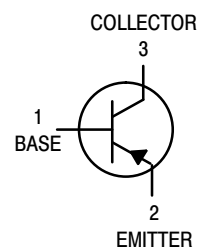
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR–5 =  $1.0 \times 0.75 \times 0.062$  in.
2. Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.



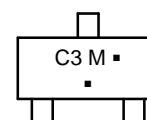
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SOT–23  
CASE 318  
STYLE 6

#### MARKING DIAGRAM



C3 = Device Code  
M = Date Code\*  
■ = Pb-Free Package

(Note: Microdot may be in either location)  
\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### ORDERING INFORMATION

| Device       | Package             | Shipping†        |
|--------------|---------------------|------------------|
| MMBT4126LT1G | SOT–23<br>(Pb–Free) | 3000/Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MMBT4126LT1G

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic   | Symbol        | Min        | Max      | Unit |
|--|---------------|------------|----------|------|
| <b>OFF CHARACTERISTICS</b>   |               |            |          |      |
| Collector–Emitter Breakdown Voltage (Note 3)<br>( $I_C = -1.0\text{ mA}$ , $I_B = 0$ )   | $V_{(BR)CEO}$ | -25        | -        | Vdc  |
| Collector–Base Breakdown Voltage<br>( $I_C = -10\text{ }\mu\text{A}$ , $I_E = 0$ )   | $V_{(BR)CBO}$ | -25        | -        | Vdc  |
| Emitter–Base Breakdown Voltage<br>( $I_E = -10\text{ }\mu\text{A}$ , $I_C = 0$ )   | $V_{(BR)EBO}$ | -4         | -        | Vdc  |
| Collector Cutoff Current<br>( $V_{CE} = -30\text{ Vdc}$ , $V_{EB} = -3.0\text{ Vdc}$ )   | $I_{CEX}$     | -          | -50      | nAdc |
| <b>ON CHARACTERISTICS (Note 3)</b>   |               |            |          |      |
| DC Current Gain<br>( $I_C = -2.0\text{ mA}$ , $V_{CE} = -1.0\text{ Vdc}$ )<br>( $I_C = -50\text{ mA}$ , $V_{CE} = -1.0\text{ Vdc}$ )   | $H_{FE}$      | 120<br>60  | 300<br>- | -    |
| Collector–Emitter Saturation Voltage<br>( $I_C = -50\text{ mA}$ , $I_B = -5.0\text{ mA}$ )   | $V_{CE(sat)}$ | -          | -0.4     | Vdc  |
| Base–Emitter Saturation Voltage<br>( $I_C = -50\text{ mA}$ , $I_B = -5.0\text{ mA}$ )  | $V_{BE(sat)}$ | -          | -0.95    | Vdc  |
| <b>SMALL–SIGNAL CHARACTERISTICS</b>  |               |            |          |      |
| Current–Gain – Bandwidth Product<br>( $I_C = -10\text{ mA}$ , $V_{CE} = -20\text{ Vdc}$ , $f = 100\text{ MHz}$ )   | $f_T$         | 250        | -        | MHz  |
| Output Capacitance<br>( $V_{CB} = -5.0\text{ Vdc}$ , $I_E = 0$ , $f = 1.0\text{ MHz}$ )  | $C_{obo}$     | -          | 4.5      | pF   |
| Input Capacitance<br>( $V_{EB} = -0.5\text{ Vdc}$ , $I_C = 0$ , $f = 1.0\text{ MHz}$ )   | $C_{ibo}$     | -          | 10       | pF   |
| Small–Signal Current Gain<br>( $I_C = -2.0\text{ mA}$ , $V_{CE} = -10\text{ Vdc}$ , $f = 1.0\text{ kHz}$ )<br>( $I_C = 10\text{ mA}$ , $V_{CE} = 20\text{ Vdc}$ , $f = 100\text{ MHz}$ ) | $h_{fe}$      | 120<br>2.5 | 480<br>- | -    |
| Noise Figure<br>( $I_C = -100\text{ }\mu\text{A}$ , $V_{CE} = -5.0\text{ Vdc}$ , $R_S = 1.0\text{ k}\Omega$ , $f = 1.0\text{ kHz}$ )   | NF            | -          | 4.0      | dB   |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Pulse Test: Pulse Width  $\leq 300\text{ }\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

## TYPICAL TRANSIENT CHARACTERISTICS

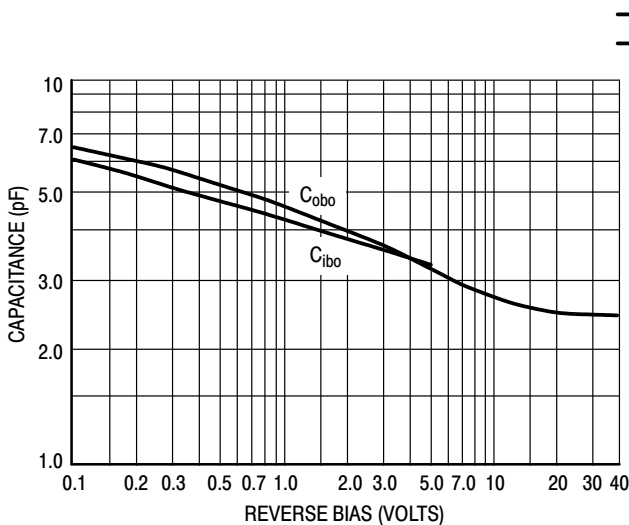


Figure 1. Capacitance

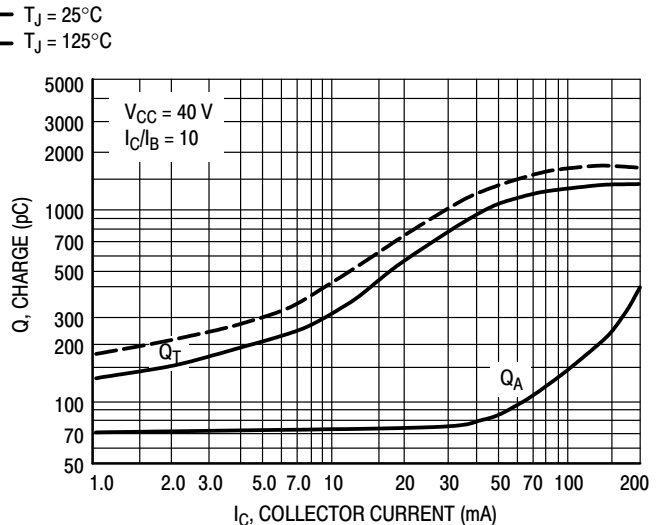


Figure 2. Charge Data

# MMBT4126LT1G

## TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

( $V_{CE} = -5.0$  Vdc,  $T_A = 25^\circ\text{C}$ , Bandwidth = 1.0 Hz)

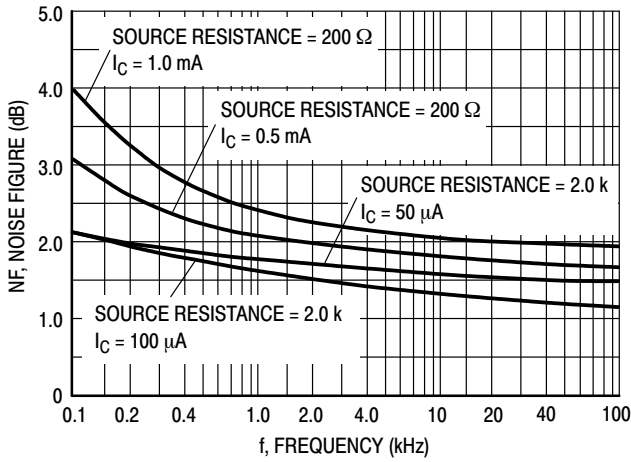


Figure 3.

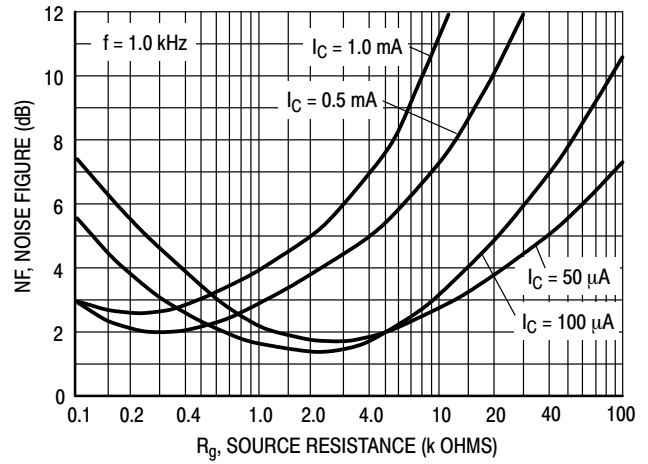


Figure 4.

## h PARAMETERS

( $V_{CE} = -10$  Vdc,  $f = 1.0$  kHz,  $T_A = 25^\circ\text{C}$ )

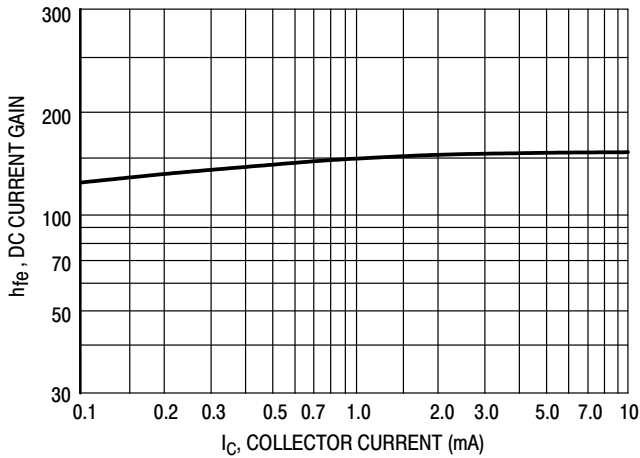


Figure 5. Current Gain

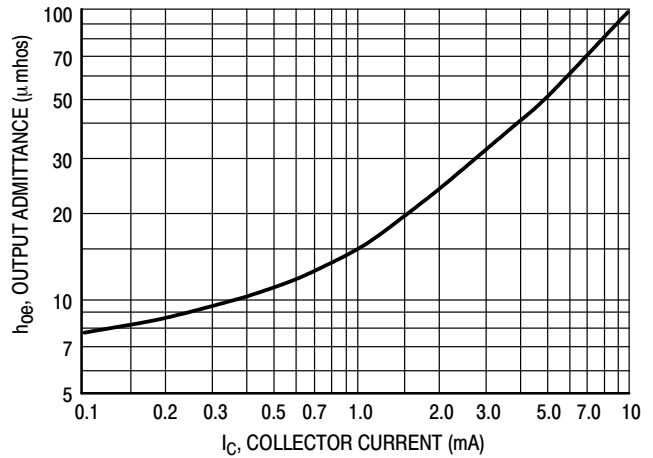


Figure 6. Output Admittance

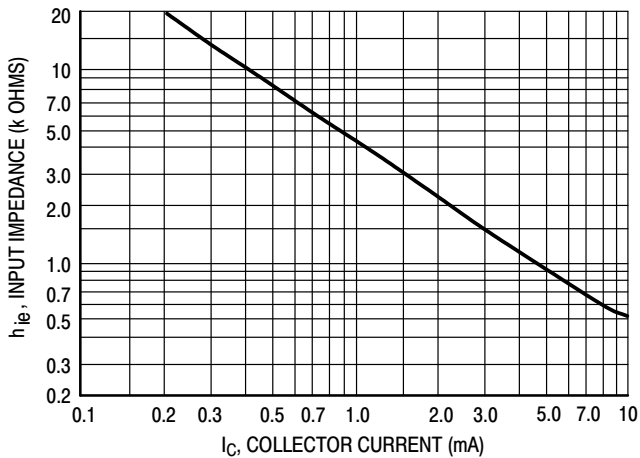


Figure 7. Input Impedance

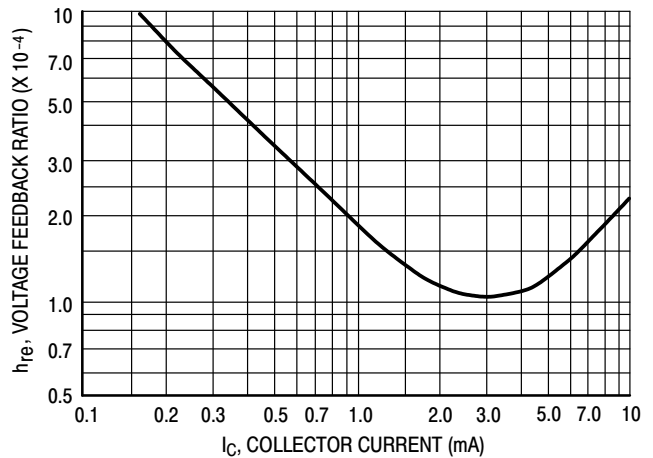


Figure 8. Voltage Feedback Ratio

# MMBT4126LT1G

## TYPICAL STATIC CHARACTERISTICS

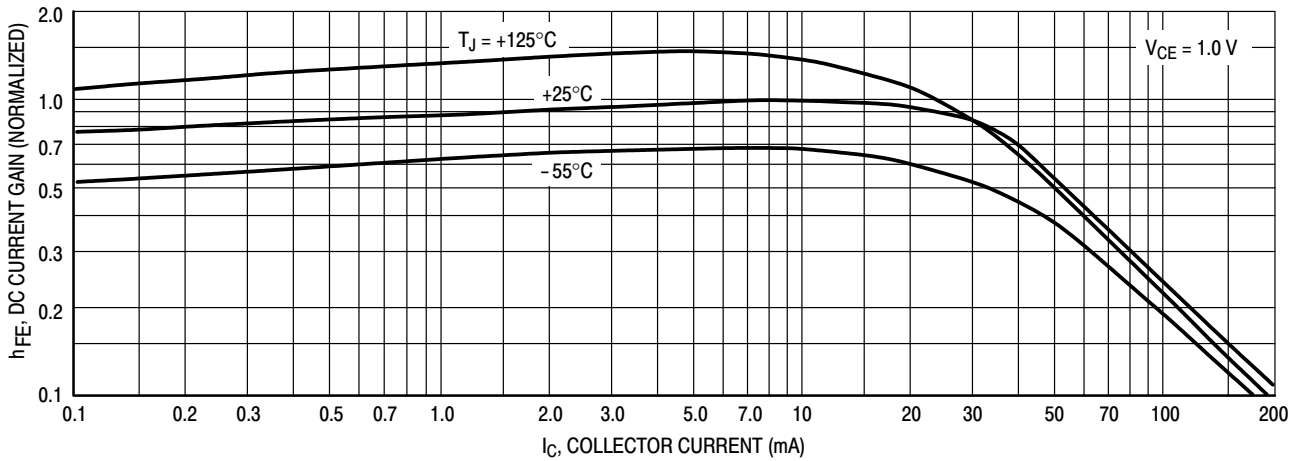


Figure 9. DC Current Gain

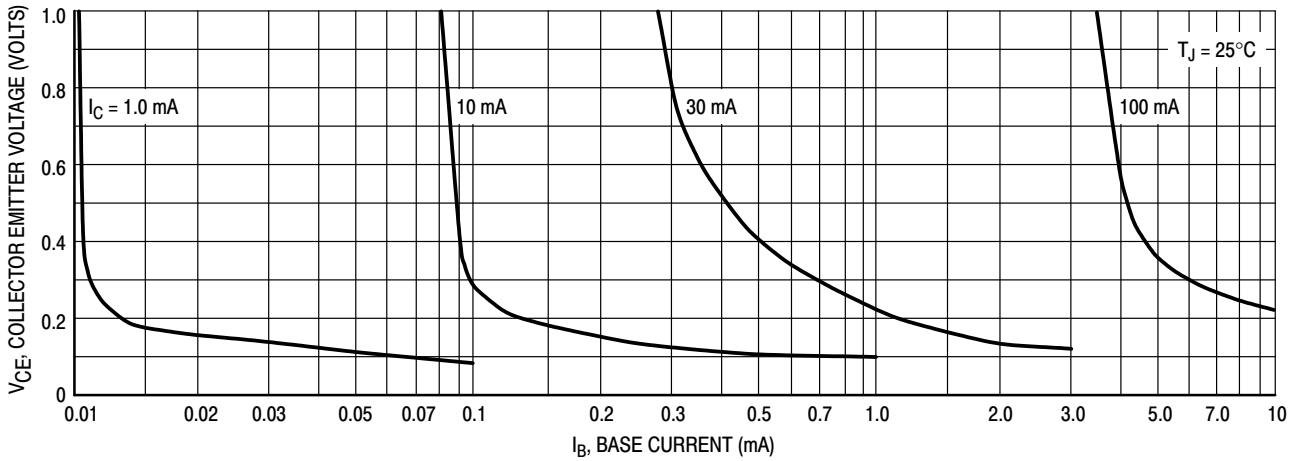


Figure 10. Collector Saturation Region

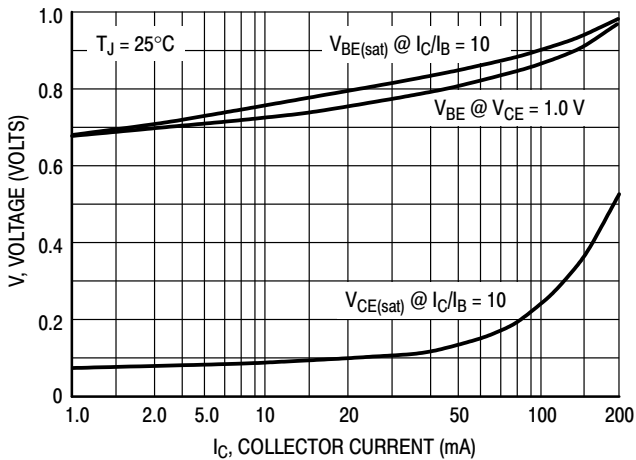


Figure 11. "ON" Voltages

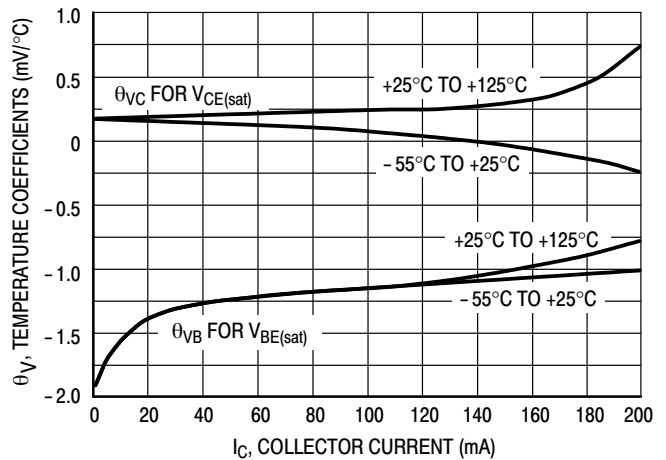


Figure 12. Temperature Coefficients

# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



**SOT-23 (TO-236)**  
CASE 318  
ISSUE AT

DATE 01 MAR 2023

SCALE 4:1



**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M,1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

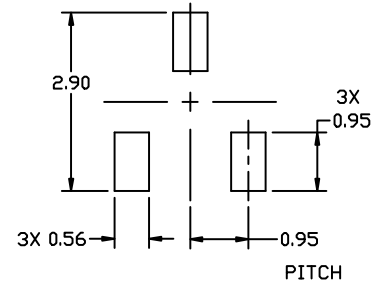
| DIM            | MILLIMETERS |      |      | INCHES |       |       |
|----------------|-------------|------|------|--------|-------|-------|
|                | MIN.        | NOM. | MAX. | MIN.   | NOM.  | MAX.  |
| A              | 0.89        | 1.00 | 1.11 | 0.035  | 0.039 | 0.044 |
| A1             | 0.01        | 0.06 | 0.10 | 0.000  | 0.002 | 0.004 |
| b              | 0.37        | 0.44 | 0.50 | 0.015  | 0.017 | 0.020 |
| c              | 0.08        | 0.14 | 0.20 | 0.003  | 0.006 | 0.008 |
| D              | 2.80        | 2.90 | 3.04 | 0.110  | 0.114 | 0.120 |
| E              | 1.20        | 1.30 | 1.40 | 0.047  | 0.051 | 0.055 |
| e              | 1.78        | 1.90 | 2.04 | 0.070  | 0.075 | 0.080 |
| L              | 0.30        | 0.43 | 0.55 | 0.012  | 0.017 | 0.022 |
| L1             | 0.35        | 0.54 | 0.69 | 0.014  | 0.021 | 0.027 |
| H <sub>E</sub> | 2.10        | 2.40 | 2.64 | 0.083  | 0.094 | 0.104 |
| T              | 0°          | ---  | 10°  | 0°     | ---   | 10°   |

**GENERIC MARKING DIAGRAM\***



- XXX = Specific Device Code
- M = Date Code
- = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.



**RECOMMENDED MOUNTING FOOTPRINT**

\* For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

**STYLES ON PAGE 2**

|                         |                        |  |
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# MECHANICAL CASE OUTLINE

## PACKAGE DIMENSIONS



### SOT-23 (TO-236) CASE 318 ISSUE AT

DATE 01 MAR 2023

|   |   |   |   |   |   |
|---|---|---|---|---|---|
| STYLE 1 THRU 5:<br>CANCELLED                            | STYLE 6:<br>PIN 1. BASE<br>2. EMITTER<br>3. COLLECTOR | STYLE 7:<br>PIN 1. EMITTER<br>2. BASE<br>3. COLLECTOR       | STYLE 8:<br>PIN 1. ANODE<br>2. NO CONNECTION<br>3. CATHODE  |   |   |
| STYLE 9:<br>PIN 1. ANODE<br>2. ANODE<br>3. CATHODE      | STYLE 10:<br>PIN 1. DRAIN<br>2. SOURCE<br>3. GATE     | STYLE 11:<br>PIN 1. ANODE<br>2. CATHODE<br>3. CATHODE-ANODE | STYLE 12:<br>PIN 1. CATHODE<br>2. CATHODE<br>3. ANODE       | STYLE 13:<br>PIN 1. SOURCE<br>2. DRAIN<br>3. GATE           | STYLE 14:<br>PIN 1. CATHODE<br>2. GATE<br>3. ANODE          |
| STYLE 15:<br>PIN 1. GATE<br>2. CATHODE<br>3. ANODE      | STYLE 16:<br>PIN 1. ANODE<br>2. CATHODE<br>3. CATHODE | STYLE 17:<br>PIN 1. NO CONNECTION<br>2. ANODE<br>3. CATHODE | STYLE 18:<br>PIN 1. NO CONNECTION<br>2. CATHODE<br>3. ANODE | STYLE 19:<br>PIN 1. CATHODE<br>2. ANODE<br>3. CATHODE-ANODE | STYLE 20:<br>PIN 1. CATHODE<br>2. ANODE<br>3. GATE          |
| STYLE 21:<br>PIN 1. GATE<br>2. SOURCE<br>3. DRAIN       | STYLE 22:<br>PIN 1. RETURN<br>2. OUTPUT<br>3. INPUT   | STYLE 23:<br>PIN 1. ANODE<br>2. ANODE<br>3. CATHODE         | STYLE 24:<br>PIN 1. GATE<br>2. DRAIN<br>3. SOURCE           | STYLE 25:<br>PIN 1. ANODE<br>2. CATHODE<br>3. GATE          | STYLE 26:<br>PIN 1. CATHODE<br>2. ANODE<br>3. NO CONNECTION |
| STYLE 27:<br>PIN 1. CATHODE<br>2. CATHODE<br>3. CATHODE | STYLE 28:<br>PIN 1. ANODE<br>2. ANODE<br>3. ANODE     |   |   |   |   |

|                         |                        |   |
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